Optimization and Implementation of Multimode Piezoelectric Shunt Damping Systems

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Abstract-Piezoelectric transducer (PZT) patches can be attached to a structure in order to reduce vibration. The PZT patches essentially convert vibrational mechanical energy into electrical energy. The electrical energy can be dissipated via an electrical impedance. Currently, impedance designs require experimental tuning of resistive circuit elements to provide optimal performance. A systematic method is presented for determining the resistance values by minimizing the \mathcal{H}_2 norm of the damped system. After the design process, shunt circuits are normally implemented using discrete resistors, virtual inductors and Riordian gyrators. The difficulty in constructing the shunt circuits and achieving reasonable performance has been an ongoing and unaddressed problem in shunt damping. A new approach to implementing piezoelectric shunt circuits is presented. A synthetic impedance, consisting of a voltage controlled current source and a digital signal processor system, is used to synthesize the terminal impedance of a shunt network. A two-mode shunt circuit is designed and implemented for an experimental simply supported beam. The second and third structural modes of the beam are reduced in magnitude by 22 and 18 dB.

Index Terms—Damping, piezoelectric, resistor, shunt, synthesis.

I. INTRODUCTION

ODAY'S increasingly highspeed and lightweight structures are subject to extensive vibrations that can reduce structural life and contribute to mechanical failure. Piezoelectric transducers (PZTs) in conjunction with appropriate circuitry, can be used as a mechanical energy dissipation device. By placing an electrical impedance across the terminals of the PZT, the passive network is capable of damping structural vibrations. If a simple resistor is placed across the terminals of the PZT, the PZT will act as a viscoelastic damper [1]. If the network consists of a series inductor-resistor R - L circuit, the passive network combined with the inherent capacitance of the PZT creates a damped electrical resonance. The resonance can be tuned so that the PZT element acts as a tuned vibrational energy absorber [1]. This damping methodology is commonly referred to as passive shunt damping. Passive shunt damping is regarded as a simple, low cost, lightweight and easy to implement method of controlling structural vibrations. A desirable property of passive shunt damping is that the controlled system is guaranteed to be stable in the presence of structural uncertainties.

Flexible mechanical structures have an infinite number of resonant frequencies (or structural modes). If the tuned energy absorber [1] is used to minimize the vibration of a number of

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Publisher Item Identifier S 1083-4435(02)02100-2.

modes, one would need an equal number of PZT patches and shunting circuits. This is clearly impractical. Wu [2] reports a method of damping multiple vibration modes using a single PZT. The proposed circuit includes a "current blocker" consisting of a parallel capacitor-inductor network placed in series with each R - L shunt circuit designed for one structural mode. Depending on the number of structural modes to be shunt damped simultaneously, a different number of C - L networks are placed in series with each parallel R - L shunt branch.

Although shunt damping circuits have a fixed structure, the designer is still faced with the problem of choosing component values. The blocking circuit and branch inductance values are easily found using classical circuit theory and the resonant frequencies of the structure. Damping resistors are currently determined experimentally by observing the frequency response of the damped system and varying the resistances to achieve a desirable tradeoff between peak reduction and side-lobe amplitude [2]–[8]. An optimization technique is proposed that minimizes the \mathcal{H}_2 norm of the damped system. This provides a systematic and reliable method for designing the resistance values of shunt damping circuits.

There are also a number of implementation problems associated with single and multimode shunt damping techniques. PZT shunt circuits typically require large inductance values. Therefore, virtual inductors are required to implement the inductor elements. Virtual inductors are large in size and sensitive to component variations and nonideal characteristics. PZT shunt circuits are capable of generating large voltages for moderate structural excitations. This requires that the virtual inductor circuits be constructed from high voltage operational amplifiers. At least 30 high voltage opamps are required to damp three structural modes.¹ This paper introduces a method of implementing a specified shunt circuit with arbitrary order and complexity. The "synthetic impedance" uses a voltage dependant current source and digital signal processor (DSP) system to implement the terminal impedance of an arbitrary shunt network. It replaces physical circuits to provide effective structural damping without the problems encountered with direct circuit implementations.

II. PIEZOELECTRIC SHUNT DAMPING

Shunt damping methodologies are often grouped into two broad categories: single mode and multimode. Single mode shunt damping techniques are simple but damp only one structural mode for every PZT. Multiple mode shunt damping techniques require more complicated shunt circuits but are capable of damping many modes.

Manuscript received March 10, 2000; revised March 9, 2001. Recommended by Technical Editor C. H. Menq. This work was supported by the Australian Research Council.

¹Based on a series circuit configuration with current blocker's in every branch, as shown in [2].



Fig. 1. Examples of shunt circuits. Single mode: (a) parallel case and (b) series case. Multimode: (c) parallel case [2] and (d) series case.

A. Single Mode Shunt Damping

Single mode damping was introduced to decrease the magnitude of one structural mode [4]. Two examples of single mode damping are shown in Fig. 1, parallel and series shunt damping. An R - L shunt circuit introduces an electrical resonance. This can be tuned to one structural mode in a manner analogous to a mechanical vibration absorber. Single mode damping can be applied to reduce several structural modes with the use of as many piezoelectric patches and damping circuits.

Problems may result if these piezoelectric patches are bonded to, or imbedded in the structure. First, the structure may not have sufficient room to accommodate all of the patches. Second, the structure may be altered or weakened when the piezoelectric patches are applied. In addition, a large number of patches can increase the structural weight, making it unsuitable for applications such as aerospace.

B. Multiple Mode Shunt Damping

To alleviate the problems associated with single mode damping, multimode shunt damping has been introduced; i.e., the use of one piezoelectric patch to damp several structural modes. There are two common circuit configurations for multimode shunt damping, parallel and series. Examples of these two configurations are shown in Fig. 1. There are other examples of multimode shunt damping but these will not be discussed in this paper.

The principle of multimode shunt damping is to insert a "current blocking" circuit [2], [6]–[8] in series with each shunt branch. In Fig. 1(d), the blocking circuit consists of a capacitor and inductor in parallel, $C_3 - L_3$ The number of antiresonant circuits in each R-L shunt branch depends on the number of structural modes to be damped simultaneously. Each R-L shunt branch is designed to damp one structural mode. For example, $R_1 - L_1$ in Fig. 1(c) is tuned to resonate at ω_1 , the resonant frequency of the first structural mode to be damped. $R_2 - L_2$ is tuned to ω_2 , the second structural mode to be damped and so on.

According to Wu [2], the inductance values for the shunt circuits shown in Fig. 1(c) and (d) can be calculated from the following expressions. It is assumed that $\omega_1 < \omega_2$

$$L_{1} = \frac{1}{\omega_{1}^{2}C_{p}}$$

$$L_{2} = \frac{\left(L_{1}\tilde{L}_{2} + \tilde{L}_{2}L_{3} - L_{1}L_{3} - \omega_{2}^{2}L_{1}\tilde{L}_{2}L_{3}C_{3}\right)}{\left(L_{1} - \tilde{L}_{2}\right)\left(1 - \omega_{2}^{2}L_{3}C_{3}\right)}$$

$$\tilde{L}_{2} = \frac{1}{\omega_{2}^{2}C_{p}}$$

$$L_{3} = \frac{1}{\omega_{1}^{2}C_{3}}$$



Fig. 2. Piezoelectric laminated simply supported beam.

where C_p is the capacitance of the PZT and C_3 is an arbitrary capacitor used in the current blocking network. In the following Sections C_3 will be taken as 100 ηF .

C. Implementation Difficulties

Currently, shunt damping circuits are implemented using a network of physical components. There are a number of problems associated with this *direct circuit* implementation, the foremost of which are listed below.

- Typically the shunt circuits require large inductor values (up to thousands of henries). Virtual grounded and floating inductors (Riordan gyrators [9]) are required to implement the inductor elements. Such virtual implementations are typically poor representations of ideal inductors. They are large in size, difficult to tune, and are sensitive to component age, temperature, and nonideal characteristics.
- Piezoelectric patches are capable of generating hundreds of volts for moderate structural excitations. This requires the entire circuit to be constructed from high voltage components. Further voltage limitations arise due to the internal gains of the virtual inductors.
- The minimum number of opamps required to implement the shunt damping circuit increases rapidly with the number of modes to be damped. At least 30 opamps are required to implement a series configuration multimode shunt damping circuit with current blocker's in every branch. The relationship between the number of opamps and the number of modes to be damped for this circuit configuration is given by Opamps = 2n + 4n(n - 1), where *n* is the number of modes to be damped.

III. MODELLING THE COMPOUND SYSTEM

In this Section we sketch how the dynamics of a simply supported piezoelectric laminate beam as illustrated in Fig. 2 can be derived. Two piezoelectric patches are bonded to the structure using a strong adhesive material. One PZT will be used as an actuator to generate a disturbance and the other as a passive shunting layer. The subscripts "*a*," "*b*," and "*s*" correspond, respectively, to the actuating piezoelectric layer, the beam and the shunting piezoelectric layer.

A. Structural Dynamics of a Simply Supported Beam

When modeling the dynamics of a structure, it is common practice to derive the transfer function between the displacement at any point along the beam and the actuator voltage, i.e., $Y(x,s)/V_a(s)$ and also the transfer function between the shunting piezoelectric voltage and the actuator voltage $V_s(s)/V_a(s)$.

The elastic deflection of a simply supported beam is described by the one dimensional Bernoulli–Euler beam equation which has been modified [10] as shown below:

$$\frac{\partial^2}{\partial x^2} \left[EI \frac{\partial^2 y(x,t)}{\partial x^2} - C_a v_a(x,t) \right] + \rho A \frac{\partial^2 y(x,t)}{\partial t^2} = 0 \quad (1)$$

where E, I, A, and ρ represent the Young's modulus, moment of inertia, cross-sectional area, and linear mass density of the beam, respectively. The additional term is due to the moment applied to the neutral axis of the beam by the actuator piezoelectric layer, i.e., $M_a = C_a v_a(x,t)$ where C_a is a constant dependent on the actuator properties [11]–[13]. It is assumed that each piezoelectric patch is very thin and that the beam deflects only in the y axis. Simply supported boundary conditions imply y(0,t) = y(L,t) = 0 and $EI(\partial^2 y(0,t))/\partial x^2 =$ $EI(\partial^2 y(L,t))/\partial x^2 = 0.$

By using the *modal analysis technique* [14] the position function y(x,t), can be expanded as an infinite series of the form $y(x,t) = \sum_{i=1}^{\infty} \phi_i(x)q_i(t)$, where $\phi_i(x)$ are the normalized mode shapes given by $\phi_i(x) = \sqrt{2/(\rho AL)} \sin((i\pi x)/L)$ [14] and $q_i(t)$ are the modal displacements [10].

To formulate the dynamical response of the system, the Lagrange equations [14] are used to find the differential equation corresponding to each mode

$$\ddot{q}_i(t) + \omega_i^2 q_i(t) = C_a \left[\phi_i'(x_1) - \phi_i'(x_2) \right] v_a(t).$$
(2)

The PZT sensor voltage can be described by $v_s(t) = C_s(\partial y(x,t))/\partial x|_{x_3}^{x_4}$ where C_s is the piezoelectric constant of the PZT [10]. In the sequel we will use the notation $(\bullet)', (\bullet)$ to represent the derivatives with respect to the spatial variable x and time t, respectively. The resonant frequencies ω_i are given by $\omega_i = ((i\pi)/L)^2 \sqrt{(EI)/(\rho A)}$.

The dynamic response is found by taking the Laplace transform of the above equation and substituting $Y_i(x,s) = \phi_i(x)q_i(s)$

$$\frac{Y(x,s)}{V_a(s)} = \sum_{i=1}^{\infty} \frac{C_a \left[\phi_i'(x_1) - \phi_i'(x_2)\right] \phi_i(x)}{s^2 + 2\zeta_i w_i s + w_i^2}.$$
 (3)

The above equation describes the elastic deflection of the entire flexible beam due to a voltage applied to the piezoelectric actuator. Note that the additional terms $2\zeta_i w_i s$, are added to compensate for structural damping and are usually found experimentally. The shunting layer voltage can be expressed as $v_s(t) = C_s \sum_{i=1}^{\infty} q_i(t)(\phi'_i(x_3) - \phi'_i(x_4))$. By taking the



Fig. 3. Shunted PZT schematic.

Laplace transform, the transfer function from the actuator to shunt voltage is found to be [15]

$$\frac{V_s(s)}{V_a(s)} = \sum_{i=1}^{\infty} \frac{C_s C_a \left[\phi_i'\left(x_1\right) - \phi_i'\left(x_2\right)\right] \left[\phi_i'\left(x_3\right) - \phi_i'\left(x_4\right)\right]}{s^2 + 2\zeta_i w_i s + w_i^2}.$$
(4)

The transfer functions $Y(x,s)/V_a(s)$ and $V_s(s)/V_a(s)$ can be represented in state-space form as

$$\dot{\mathbf{x}}_{\mathbf{b}} = \mathbf{A}\mathbf{x}_{b} + \mathbf{B}V_{a}$$

$$Y = \mathbf{C}_{Y}\mathbf{x}_{b}$$

$$V_{s} = \mathbf{C}_{V_{s}}\mathbf{x}_{b}$$
(5)

where x_b is the beam state vector, and \mathbf{C}_Y and \mathbf{C}_{V_s} depend on Y(x,s) and $V_s(s)$.

B. Compound Dynamics

As discussed in Section II-B, there are two common circuit configurations used for multimode shunt damping, series and parallel as shown in Fig. 1. In order to model the presence of the shunt network, the coupled terminal dynamics of the circuit and laminated beam are considered.

Piezoelectric transducers behave electrically like a capacitor C_p and mechanically like a stiff spring. It is common to model the piezoelectric element as a capacitor C_p in series with a strain dependent voltage source [1], [16]. Consider Figs. 2 and 3, where a piezoelectric patch is shunted with an impedance Z. The current-voltage relation of the impedance can be represented in state-space form as

$$\dot{\mathbf{x}}_z = \mathbf{A}_z \mathbf{x}_z + \mathbf{B}_z V_z \tag{6}$$

$$i_z = \mathbf{C}_z x_z + \mathbf{D}_z V_z \tag{7}$$

where V_z is the voltage across the impedance and i_z is the current flowing through the circuit. The relationship between V_z and V_p , shown in Figs. 2 and 3, is

$$\dot{\mathbf{x}}_b = \mathbf{A}\mathbf{x}_b + \mathbf{B}V_z \tag{8}$$

$$V_p = -\mathbf{C}_{V_s} \mathbf{x}_b \tag{9}$$

where V_p is the voltage induced from the electromechanical coupling effect. By shunting the piezoelectric patch, the voltage V_z across the shunting layer or impedance, is related to the terminal voltage and current by

$$V_z = V_p - \frac{1}{C_p} \int i_z dt.$$
 (10)

The variable i_z , can be replaced with $\dot{\mathbf{q}}_z$, the charge on the PZT. Consequently, by replacing V_z and substituting $V_p = -\mathbf{C}_{V_s}\mathbf{x}_b$ (6)–(8) become

$$\begin{bmatrix} \dot{\mathbf{x}}_b \\ \dot{\mathbf{x}}_z \\ \dot{\mathbf{q}}_z \end{bmatrix} = \begin{bmatrix} \mathbf{A} - \mathbf{B}\mathbf{C}_{V_s} & \mathbf{0} & -\frac{1}{C_p}\mathbf{B} \\ -\mathbf{B}_z\mathbf{C}_{V_s} & \mathbf{A}_z & -\frac{1}{C_p}\mathbf{B}_z \\ -\mathbf{D}_z\mathbf{C}_{V_s} & \mathbf{C}_z & -\frac{1}{C_p}\mathbf{D}_z \end{bmatrix} \begin{bmatrix} \mathbf{x}_b \\ \mathbf{x}_z \\ \mathbf{q}_z \end{bmatrix}.$$
 (11)

If a voltage V_a is applied to the actuator PZT, then (11) becomes

$$\dot{\mathbf{X}} = \tilde{\mathbf{A}}\mathbf{X} + \tilde{\mathbf{B}}V_a$$

$$V_z = \tilde{\mathbf{C}}_{V_s}\mathbf{X}$$

$$Y = \tilde{\mathbf{C}}_Y\mathbf{X}.$$
(12)

where $\mathbf{X} = [\mathbf{x}_b \ \mathbf{x}_z \ \mathbf{q}_z]^T$, $\tilde{\mathbf{B}} = [\mathbf{B} \ \mathbf{0} \ \mathbf{0}]^T$, $\tilde{\mathbf{C}}_{V_s} = [\mathbf{C}_{V_s} \ \mathbf{0} \ \mathbf{0}]^T$, and $\tilde{\mathbf{C}}_Y = [\mathbf{C}_Y \ \mathbf{0} \ \mathbf{0}]^T$.

IV. DETERMINING THE SHUNTING RESISTANCES VIA OPTIMIZATION

In order to find appropriate values for the shunt resistors $\mathbf{R} = \{\mathbf{R_1}, \mathbf{R_2}, \dots, \mathbf{R_n}\}$ an optimization approach is proposed; a set of resistors can be found so that the \mathcal{H}_2 norm of the damped system is minimized. Minimizing the \mathcal{H}_2 norm of the system minimizes the RMS displacement at a single, or series of points due to a spectrally white disturbance signal applied to the actuator(s).

A. Optimization Technique

Consider a transfer function matrix $\tilde{\mathbf{G}}(s) \in \mathbb{C}^{m \times n}$ representing the damped system (12). The \mathcal{H}_2 norm of $\tilde{\mathbf{G}}(s)$, denoted $||\tilde{\mathbf{G}}(s)||_2$, is defined as

$$\left\|\tilde{\mathbf{G}}(s)\right\|_{2}^{2} = \frac{1}{2\pi} \int_{-\infty}^{\infty} \operatorname{tr}\left(\tilde{\mathbf{G}}^{\mathbf{T}}(-\mathbf{j}\omega)\tilde{\mathbf{G}}(\mathbf{j}\omega)\mathbf{d}\omega\right).$$

Let $\tilde{\mathbf{G}}(s)$ have the realization $\tilde{\mathbf{G}}(s) = \tilde{\mathbf{C}}(s\mathbf{I} - \tilde{\mathbf{A}})^{-1}\tilde{\mathbf{B}}$. If the matrix $\tilde{\mathbf{A}}$ is stable the following equality holds:

$$J = \|\mathbf{G}(s)\|_{2}^{2} = \operatorname{tr}\left(\tilde{\mathbf{C}}\mathbf{P}\tilde{\mathbf{C}}^{T}\right)$$
(13)

where **P** satisfies the *Lyapunov* equation $\tilde{\mathbf{A}}^T(\mathbf{R})\mathbf{P}+\mathbf{P}\tilde{\mathbf{A}}(\mathbf{R})+\tilde{\mathbf{B}}\tilde{\mathbf{B}}^T = \mathbf{0}$. This leads to the following constrained optimization problem:

$$\mathbf{R}^* = \arg\min_{\mathbf{s.t. g=0}} \mathbf{J}$$
(14)

where $\mathbf{g} = \tilde{\mathbf{A}}^T \mathbf{P} + \mathbf{P} \tilde{\mathbf{A}} + \tilde{\mathbf{B}} \tilde{\mathbf{B}}^T$ and $\mathbf{R} = \{\mathbf{R_1}, \mathbf{R_2}, \dots, \mathbf{R_n}\},\ R_1, R_2, \dots, R_n > 0.$

Having set up the optimization problem (14), a number of methods can be employed to find an optimal set of resistors $\mathbf{R}^* = {\mathbf{R}_1^*, \mathbf{R}_2^*, \dots, \mathbf{R}_n^*}$. One such method is the Nelder-Mead simplex search algorithm. A more elegant and computationally efficient method of solving (14) is to use the gradient search algorithm. By introducing the matrix of Lagrange multipliers S the Lagrangian L is formed as follows:

$$L = \operatorname{tr}\left(\tilde{\mathbf{C}}\mathbf{P}\tilde{\mathbf{C}}^{T}\right) + \operatorname{tr}(\mathbf{g}\mathbf{S}).$$
(15)

The first-order necessary conditions for optimality are found by equating the derivatives of L with respect to the parameters **P**, **S**, and **R** to zero

$$\frac{\partial L}{\partial \mathbf{S}} = \tilde{\mathbf{A}} \mathbf{P} + \mathbf{P} \tilde{\mathbf{A}}^{T} + \tilde{\mathbf{B}} \tilde{\mathbf{B}}^{T} = \mathbf{0}$$
(16)

$$\frac{\partial L}{\partial \mathbf{P}} = \tilde{\mathbf{A}}^T \mathbf{S} + \mathbf{S}\tilde{\mathbf{A}} + \tilde{\mathbf{C}}^T \tilde{\mathbf{C}} = \mathbf{0}$$
(17)
$$\frac{\partial L}{\partial R_1} = \operatorname{tr} \left(\tilde{\mathbf{E}}_1 \mathbf{P} \mathbf{S} + \mathbf{P} \tilde{\mathbf{E}}_1^T \mathbf{S} \right) = 0$$

$$\vdots$$

$$\frac{\partial L}{\partial R_n} = \operatorname{tr} \left(\tilde{\mathbf{E}}_n \mathbf{P} \mathbf{S} + \mathbf{P} \tilde{\mathbf{E}}_n^T \mathbf{S} \right) = 0.$$
(18)

With *n* resistors, $\tilde{\mathbf{A}}$ can be represented as $\tilde{\mathbf{A}} = \hat{\mathbf{A}} + \mathbf{R_1}\tilde{\mathbf{E_1}} + \cdots + \mathbf{R_n}\tilde{\mathbf{E_n}}$, where $\hat{\mathbf{A}}$ is independent of \mathbf{R} .

The \mathcal{H}_2 norm of the system can now be minimized by solving the above equations simultaneously. It is not possible to obtain a closed form solution, so a numerical approach is required.

As preliminaries for the optimization, the static matrices ($\hat{\mathbf{B}}$ and $\tilde{\mathbf{C}}$) are computed and an initial estimate $\mathbf{R_0}$ is made for \mathbf{R}^* . Matrix $\tilde{\mathbf{A}}$ is a function of $\mathbf{R_k}$ and is updated at each iteration. Matrices \mathbf{P} and \mathbf{S} , are calculated by solving the Lyapunov equations (16) and (17). The direction of steepest descent is found by evaluating the gradient vector, whose entries are the partial derivatives of L with respect to R_1, R_2, \ldots, R_n (18). The process is iterated by updating $\mathbf{R_k}$ until a minima is obtained (i.e., until the exiting conditions $\partial L/\partial R_i \approx 0$ and $L_{k+1} \approx L_k$ are satisfied).

V. IMPLEMENTATION OF SHUNT DAMPING CIRCUITS

It should be clear from previous sections that although the concept of multimode shunt damping is useful, implementation difficulties make its application somewhat limited. This section introduces a new method of implementing complicated shunt damping circuits using only a few opamps, one resistor, and a DSP.

A. Synthetic Impedance

We define a "synthetic impedance" as a two terminal device that establishes an arbitrary relationship between voltage and current at its terminals. The functionality is shown in Fig. 4, where $i_z(t) = f(v_z(t))$. This can be made to synthesize any network of physical components by fixing i_z to be the output of a linear transfer function of v_z . i.e.

$$I_z(s) = Y(s)V_z(s) \tag{19}$$

where $Y(s) \equiv 1/(Z(s))$ and Z(s) is the impedance to be seen from the terminals. The transfer function Y(s) can be implemented with an analog filter or DSP system. A DSP system is used here for flexibility and ease of implementation.



Fig. 4. Current source implementation.

B. Synthesis of Piezoelectric Shunt Damping Circuits

A synthetic impedance that implements the multimode shunt damping circuit shown in Fig. 1(d) will now be designed.

The implementing circuit is similar to the example implementation shown in Fig. 4. A voltage controlled current source constructed from a single opamp is used together with buffer/amplifiers and a DSP system to simulate an impedance. The two unity gain buffers are replaced with noninverting amplifiers of gain 1/10 and 10. This retains the functionality while allowing the DSP system to operate at a voltage ten times lower than that dealt with by the current source and buffer/amplifiers. A voltage protection device is placed at the input to the DSP analog to digital converter. The only required high voltage components are now the buffer/amplifier and current source opamp. The resistor R_c sets the transconductance gain of the system. In order to minimize quantization error, a reasonable portion of the digital to analog converters range should be utilized. A larger resistor requires a larger voltage to provide a specified current. To maintain a unity transconductance, a gain equal to the value of the resistance R_c should be placed internally in the DSP algorithm.

The DSP system should be programmed to implement the admittance transfer function of the damping network. In this paper, Simulink² and the Real Time Workshop for Matlab are used to generate the DSP application.³

VI. EXPERIMENTAL RESULTS

To assess the merit of the concepts presented, a number of experiments were carried out on a simply supported piezoelectic laminate beam. By identifying the resonant frequencies and damping ratios of the beam, a 5-mode (tenth order) truncated model is constructed. The optimization technique described in Section IV-A is then employed to determine the optimal shunt resistances. Finally, the optimal parallel and series shunt circuits are synthesized and applied to the structure. Damping performance is evaluated by measuring the free and damped frequency responses of the beam.

A. Experimental Setup

The experimental beam is a uniform aluminum bar with rectangular cross section and experimentally pinned boundary con-

TABLE I Beam Parameters

Length, L	0.6 m
Width, w_b	$0.05 \ m$
Thickness, h_b	$0.003 \ m$
Young's Modulus, E_b	$65 imes 10^9~N/m^2$
Density, ρ	$2650 \ kg/m^2$

TABLE II Peizoelectric Parameters

Length	$0.070 \ m$
Charge Constant, d_{31}	$-210 imes 10^{-12} \ m/V$
Voltage Constant, g_{31}	$-11.5 \times 10^{-3} \ Vm/N$
Coupling Coefficient, k_{31}	0.340
Capacitance, C_p	$0.105 \ \mu F$
Width, $w_s w_a$	$0.025 \ m$
Thickness, $h_s h_a$	$0.25 imes 10^{-3}~m$
Young's Modulus, $E_s E_a$	$63 imes 10^9 \; N/m^2$

ditions at both ends. A pair of piezoelectric ceramic patches (PIC151) are attached symmetrically to either side of the beam surface. One patch is used as an actuator and the other as a shunting layer. Experimental beam and piezoelectric parameters are summarized in Tables I and II.

The displacement and voltage frequency responses are measured using a Polytec laser vibrometer (PSV-300) and a HP spectrum analyzer (35670A). In both cases a swept sine excitation is applied to the actuator PZT.

The current source and buffer/amplifiers required for the synthetic impedance are constructed from Burr Brown OPA445 opamps. These opamps have a supply voltage limit of ± 45 v. For applications requiring higher terminal voltages, high voltage opamps are required. Such devices, specifically designed for driving piezoelectric transducers, are readily available.

B. Optimization Results

In order to perform the optimization, an accurate model of the system is required. For obvious reasons the infinite-order model produced by the modal analysis technique is not suitable for use in the optimization. As an alternative, the displacement and voltage frequency responses are measured and used to tune a finite-order model with the following structure:

$$G_{yv}(s) = \frac{Y(0.170, s)}{V_a(s)} = \sum_{i=1}^{5} \frac{Fy_i}{s^2 + 2\zeta_i \omega_i s + \omega_i^2} + Ky_{\text{opt}}$$
$$G_{vv}(s) = \frac{V_s(s)}{V_a(s)} = \sum_{i=1}^{5} \frac{Fv_i}{s^2 + 2\zeta_i \omega_i s + \omega_i^2} + Kv_{\text{opt}}$$

where Ky_{opt} and Kv_{opt} are the zero frequency correction terms introduced in [15]. The frequency response of the experimental

²A graphical simulation environment for Matlab.

 $^{^3} The target processing hardware is the dSPACE ds1103 processing and I/O board.$



Fig. 5. Frequency response of (a) $V_s(s)$)/ $(V_a(s)$, (b) $d(0.170, s)/V_a(s)$. Experimental (· · ·) modeled (—).

system and identified model is shown in Fig. 5. It is observed that the identified model is a good representation of the true system over the bandwidth of interest.

Although the truncated model can be found to minimize the \mathcal{H}_2 norm of the additive error system [15], the inherent feed through K_{opt} causes the \mathcal{H}_2 norm of the corrected system to approach infinity. To overcome this adverse effect, the corrected

system $\begin{vmatrix} \mathbf{A}_c & \mathbf{B}_c \\ \mathbf{C}_c & \mathbf{D}_c \end{vmatrix}$ is remodeled with an additional parallel

low-pass filter $G_f(s) = \alpha/(s^2+2\zeta\omega_c s+\omega_c^2)$. If $\omega_c \gg \max(\omega_i)$ and $\alpha/\omega_c^2 = K_{\text{opt}}$, the dynamics of the system over the bandwidth of interest are retained. The state-space realization becomes

$$\begin{bmatrix} \mathbf{A}_c & \mathbf{0} & \mathbf{B}_c \\ 0 & \mathbf{A}_f & \mathbf{B}_f \\ \hline \mathbf{C}_c & \mathbf{C}_f & \mathbf{0} \end{bmatrix}$$
(20)

where

$$\begin{bmatrix} \mathbf{A}_f & \mathbf{B}_f \\ \hline \mathbf{C}_f & \mathbf{D}_f \end{bmatrix}$$

is the state-space realization of the filter $G_f(s)$. Note that the feed through term \mathbf{D}_c has been eliminated. Because the controller is of fixed structure, the dynamics of the introduced filter will not effect the optimization. The technique presented in Section IV-A can now be applied.

With the aim of damping the second and third structural modes, the optimization is performed for both the series and parallel circuit configurations. The second and third modes are chosen for their high resonant peaks and because the location of the PZT provides the greatest authority over these two modes. (See [17] for a discussion of PZT placement issues.) The cost surfaces and a summary of the optimization results are shown in Figs. 6 and 7 and Table III.



Fig. 6. Cost surface-parallel case.



Fig. 7. Cost surface—series case.

TABLE III Optimization Circuit Parameters

	Parallel	Series
R_1	273.8 k Ω	1543.4 Ω
R_2	550.7 k Ω	1145.0 Ω
L_1	43 H	43 H
L_2	20.9 H	20.9 H
\hat{L}_2	45.2 H	45.2 H

In an earlier report where experimental tuning is performed [6], Wu makes the observation that the parallel circuit is easier to tune. This claim is justified by Figs. 6 and 7 that clearly show a greater sensitivity to resistance variations in the series cost surface.

C. Damping Performance

The optimized series and parallel shunt circuits are now applied to the beam. As shown in Section V-B, the admittance of the damping network is formed, compiled, then downloaded onto the DSP hardware. The dSPACE DS1103 processing and I/O board was chosen as the target DSP hardware.



Fig. 8. $|d(0.170, s)/V_a(s)|$ Experimental (· · ·) and theoretical (—).



Fig. 9. Experimental time domain results.

Fig. 8 shows the theoretical and experimental damped frequency response. Fig. 9 shows the experimental time domain response to a filtered step disturbance (bandpass filtered between 40 and 200 Hz). A summary of the performance is provided in Table IV

It is noted that the same experiments have been performed using discrete resistors, virtual inductors, and Riordan gyrators [18]. Nonidealities in the virtual inductors result in a poor correlation between experimental and predicted frequency responses. Peak damping performance is 3–5 dB lower than that achieved here.

The synthetic impedance has proven to be a high performance method of implementing shunt damping circuits. It has a low number of high voltage components, is immune to component nonideality and requires no tuning of sensitive virtual circuits.

VII. CONCLUSIONS

Modern high performance design specifications have given rise to the widespread use of lightweight structures. These structures

TABLE IV DAMPING PERFORMANCE

	Parallel	Series
1st Mode Reduction	$21 \; dB$	$22 \ dB$
2nd Mode Reduction	$18 \ dB$	$19 \ dB$
Undamped Settling Time Damped Settling Time	$\frac{1}{10}$	$\frac{1}{10}$

are prone to undesirable resonant vibrations that can reduce structural life and contribute to mechanical failure. Considerable research has been undertaken with the aim of damping these vibrations using a piezoelectric transducer and shunt damping circuit. Results to date have been encouraging but have lacked a systematic solution and practical implementation.

Previous design techniques have relied on the experimental tuning of circuit parameters to provide adequate performance. By modeling the compound system, an optimization problem has been formulated that minimizes the \mathcal{H}_2 norm of the resulting system. This provides a systematic procedure for designing fixed structure shunt damping circuits.

Previous shunt damping methodologies have also suffered from issues relating to the difficulty in implementing the shunt network. A synthetic impedance has been presented that implements the terminal impedance of a specified shunt network. The concepts presented have been experimentally verified with good results. The modal resonant magnitudes have been reduced by up to 22 dB, this corresponds to a damped settling time 1/10th that of the free response.⁴ In general, theoretical predictions have been coherent with experimental results.

Future work will involve remodeling the shunt damping problem in a feedback control systems perspective. This is now possible as an impedance of arbitrary structure can be implemented.

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⁴For the excitation described in Section VI-C.

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parameter systems.



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